NSN 5961-00-412-0058

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-412-0058 **Inclosure Material:** Glass **Overall Length:** 0.295 inches **Overall Diameter:** 0.093 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 8.0 breakdown voltage, dc **Special Features:** The voltage rating is a value iaw dwg no. 152-0446-01 fscm 80009; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No